PWM Speed Control for Permanent Excited DC Motors

Description

The monolithic integrated bipolar circuit U2350B is a MOSFET or IGBT-control (Insulated-Gate-Bipolar-Transistor) circuit working on the principle of pulse width modulation (PWM). The overall concept enables the construction of a power controller with mains voltage

compensation, intermittent operation also being possible. In addition, the circuit also enables mains voltage compensated current control, which maintains the power supplied at a constant level after preset threshold has been exceeded.

Features

- Pulse width control up to 30 kHz clock frequency
- Mains supply compensation
- Current regulation
- Temperature monitoring with indicator
- Active operation indicator
- Blink-warn indicator

- Switchable to interval operation
- Push-pull output stage for separate supply
- Supply voltage monitoring
- Temperature compensated supply voltage limitation

Package: DIP 16, SO 16

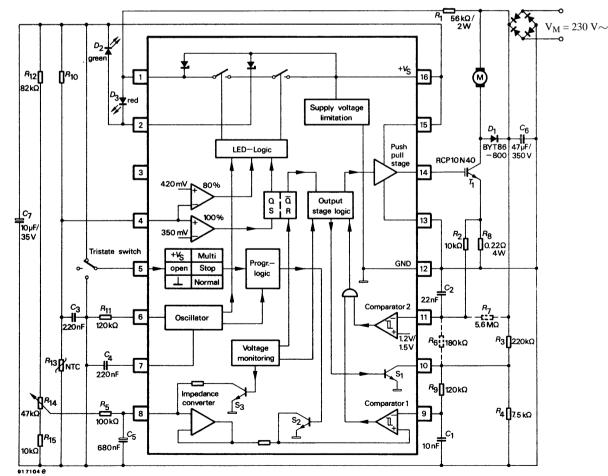


Figure 1. Block diagram with external circuitry

General Description

Supply

Internal voltage limiter in the U2350B enables a simple supply from the rectified line voltage. The supply voltage between pin 16 (+V_S) and pin 12 (ground) is built up via R₁ and is smoothed by C₇. The typically 5 mA supply current is simultaneously used to operate the two LEDs D₂, D₃, which can both be bridged internally. The supply current therefore reaches pin 16 either via LEDs or the internal switches (V_{sat} \leq 1.2 V).

Series resistor R₁ can be calculated as follows:

$$R_{1max} = \frac{V_{Mmin} - V_{Smax}}{I_{tot}} whereas$$

 $V_{Mmin} = V_{Mains} - 15\%$

 $V_{Smax} = maximum \ supply \ voltage$

 $I_{tot} = I_{Smax} + I_x$

 $I_{Smax} = Max.$ current consumption of the IC

 I_x = Current consumption of the external components

Here, C_6 must be so selected that voltage at C_7 (figure 1) is not noticeable affected by the load in any mode of operation. Further information regarding mains power supply, refer to figures 5 and 6.

Voltage Monitoring

Whilst the operation voltage is being built up or reduced, uncontrolled output pulses of insufficient amplitude are being suppressed by the internal monitoring circuit. The latch is also reset, the LED D_2 (operating indicator) between pin 2 and pin 16 is switched off and the control input pin 8 is connected to ground via switch S_3 and a 1 k Ω resistor. In connection with a switching hysteresis of approximately 2 V, this mode of operation guarantees fail-safe start-up each time the operating voltage is switched on, in the same way as after short mains interruptions.

Connecting the control input pin 8 with a capacitor can therefore make possible a soft start with rapid recovery.

Pulse Width Control with Mains Voltage Compensation

Average value of the voltage over the load is controlled to a infinitely selectable value by the comparator Comp. 1 with hysteresis. The rectified mains voltage is divided by R_3 and R_4 and lead in pin 10. The capacitor C_1 is charged via R₉ until the voltage V₉, which is present at the inverting input of Comp. 1, is more positive than the control voltage V₈ arriving at the non-inverting input via an impedance converter. During the charge time, which is dependent of the mains voltage, the pulse output is at high potential and the switching output pin 10 is open. If V_9 now becomes greater than V_{10} , the output from Comp. 1 switches over the output stage logic via an AND gate. The output stage logic now brings V14 to low potential and closes the switching output pin 10. This has the effect of discharging C_1 via R_9 and the switch S_1 until the approximately 300 mV hysteresis of the comparator is completed. The discharge time is dependent on the control voltage V₈. Comp. 1 then switches over again and the cycle begins once more (see figure 2). This two-state controller compensates the influence of the mains voltage, with the result that the motor voltage or motor speed is largely determined by the magnitude of the control voltage.

Current Control, Pin 11

If the current flowing through the IGBT (or MOSFET) and the shunt resistor R_8 becomes so great that a voltage greater than 1.5 V arises at pin 11, a second control loop formed with the comparator Comp. 2 becomes active, and overrides the first control loop via an AND gate. This causes the average value of the current fed to the motor to be controlled to a constant value. This in turn results in a speed which decreases greatly with the torque (see figure 3).

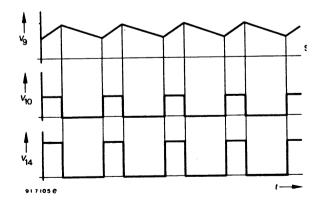


Figure 2. Pulse width control signal pattern

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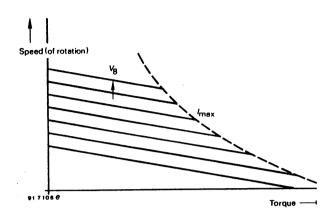


Figure 3. Influence of current control on the characteristic (curve) of a motor

By exceeding the maximum current which is adjustable with R_8 , the control dependent voltage V_8 (shunt characteristic) reaches the dotted lines (series characteristic). By applying a current which depends on the load voltage across R_6 , the constant value of the current can be further influenced. In addition, the current control limits the starting current.

In the case of effective current limiting, alteration of the rectified mains voltage has an effect on the power taken up. In order to compensate for this influence, the resistor R_7 is connected to pin 11. If dimensioned appropriately, the consumed power is dependent of changes in the mains voltage within a wide range of this voltage.

Operation Mode Selection, Pin 5

It is possible to program three modes of operation with the tristate input, as follows:

- a) Intermittent operation (pin 5 connected to $+V_S$) A signal emitted by an internal oscillator (see figure 4) switches the output stage ON and OFF periodically via S₂. This intermittent operation is very suitable for certain uses.
- b) Stop function (pin 5 open) The output is continuously switched off, the motor is at reset.
- c) Normal function (pin 5 connected to V_{12}) The output is enabled, the motor is running continuously.

Temperature Monitoring, Pin 4

The circuit also has a monitoring input. To this can be connected, for example, a NTC-resistor which functions as a temperature sensor, which is also connected via R_{10} to V_S. If the voltage V_4 falls below the first threshold V_{T80} (approximately 420 mV) as a result of the increasing temperature, an external LED D₃, which is connected between pin 1 and pin 2, starts to blink. If the temperature increases further and the voltage V₄ falls below a second threshold V_{T100} (approximately 350 mV), a latch is set. The latch makes this LED light up continuously, the output stage is blocked, the motor is switched-OFF and remains switched-OFF until the temperature has fallen and until the mains voltage is switched-OFF and switched-ON again (the latch is solely reset by the voltage monitor). A second LED D₂, which is connected between pin 2 and pin 16 and which is continuously illuminated (switch-ON) during normal operation, is switched-OFF.

In the event of wire breakage in the sensor branch, pin 4 is pulled up to $+V_S$. After the switch-OFF threshold V_{TOFF} (approximately V_{S} -1.8 V) has been exceeded, the circuit ensures that the latch is set here too. This guarantees safe operation.

Absolute Maximum Ratings

Reference point pin 12, unless otherwise specified.

Parameters	Symbol	Value	Unit			
Current requirement						
	I ₁₆	30	mA			
$t \le 10 \ \mu s$	i ₁₆	60	mA			
Push-pull output						
$V_{13} \le V_{14} \le V_{15}; V_{15} \le V_{16}, V_{13} \le V_{12}$						
Output current	I ₁₄	20	mA			
$t \le 2 ms$	i ₁₄	200	mA			
Signal output						
Input current	I _{1,2}	30	mA			
$t \le 10 \ \mu s$	i _{1,2}	60	mA			
Input currents						
R-Oscillator	I ₆	1	mA			
Control input	I ₈	1	mA			
Switch S ₁	I ₁₀	10	mA			
Input voltages pin 4, 5, 7, 9, 10, 11	VI	0 V to V ₁₆				
Storage temperature range	T _{stg}	-40 to +125	°C			
Junction temperature	Tj	+125	°C			
Ambient temperature range	T _{amb}	-10 to +100	°C			

Thermal Resistance

Parameters		Symbol	Value	Unit
Junction ambient				
	DIP 16	R _{thJA}	120	K/W
	SO 16 on PC board	R _{thJA}	180	K/W
	SO 16 on ceramic	R _{thJA}	100	K/W

Electrical Characteristics

Parameters	Test Conditions / Pins	Symbol	Min.	Тур.	Max.	Unit
Supply voltage limitation, p	vin 16					
	$I_S = 5 \text{ mA}$	VS	16.2		17.2	V
	$I_S = 20 \text{ mA}$	VS	16.3		17.8	V
Current requirement		Is			3.5	mA
Voltage monitoring, pin 16	1	1		1	1	
Switch-on threshold		V _{Son}		14.0	14.5	V
Switch-off threshold		V _{Soff}	12.0	12.5		V
Control input, pin 8	1	1		1	1	1
Input control range		VI	0		7.5	V
Input quiescent current		I _{IB}			250	nA
Impedance at lower voltage		RI		1		kΩ
Comp. 1, pin 9	1	1		1	1	
Input quiescent current		I _{IB}			250	nA
Input voltage range		V _{IC}	0		7.5	V
Hysteresis	$V_8 = 1.5 V$, pin 8 – 9	V _{Hys}	270	300	330	mV
Delay time	Pin 9 –14	t _d			3	μs
Switch S1, pin 10	1	i		i	1	i
Leakage current	$V_{10} = 15.5 V, V_8 = 3 V,$ $V_9 = 0 V, V_{11} = 0 V$	I _R			1	μΑ
Saturation voltage	$I_{10} = 2 \text{ mA}, V_8 = 0 \text{ V}, V_9 = 3 \text{ V}$	V _{sat}			0.25	V
Delay time (output)	Rising edge, pin 10 – 14 Falling edge, pin 10 – 14	t _d t _d			33	μs μs
Comp. 2, pin 11					1	, ·
Input current		II			1	μΑ
Switch-on threshold		V _{TON}	1.12	1.20	1.28	V
Switch-off threshold		V _{TOFF}	1.42	1.50	1.58	V
Delay time (output)	Pin 11 – 14	t _d			3	μs
Push-pull stage, pin 14	•					
Saturation voltage, high side	$I_{14} = -10 \text{ mA}, V_{15} = V_{16},$ pin 14 - 16	V _{SatH}			2.4	V
Saturation voltage, low side	$I_{14} = 10 \text{ mA}, V_{13} = V_{12}$	V _{SatL}			1.2	V
Output current limitation	$V_{14} = V_{12}, V_{11} = 0 V,$ $V_8 = 3 V, V_9 = 0 V, t \le 1 \mu s$	-I _O	100	150	250	mA
	$V_{14} = V_{16}$, $V_8 = 0$ V, $V_9 = 3$ V, $t \le 1 \ \mu s$	I _O	100	150	250	mA
Rise time	$V_{15} = V_{16}, V_{13} = V_{12},$ $C_{Gate} = 1 \text{ nF}$	t _r		300		ns
Fall time	$V_{15} = V_{16}, V_{13} = V_{12}, \\ C_{Gate} = 1 \text{ nF}$	t _f		800		ns
Signal outputs						
Operating indicator	$I_2 = 5 \text{ mA}$					
Saturation voltage	$V_{16} \le V_{\text{Soff}} \text{ or } V_4 \le V_{\text{T100}},$ pin 2 – 16	V _{Sat}		1.0		V

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Parameters	Test Conditions / Pins	Symbol	Min.	Тур.	Max.	Unit
Voltage limitation	$V_{16} \ge V_{Son}, V_4 > V_{T100},$ pin 2 - 16	V _{limit}		6.6		V
Overload output	$I_1 = 5 \text{ mA}$					
Saturation voltage	$V_4 > V_{T80}$, pin 1 – 2	V _{Sat}		1.0		V
Voltage limitation	$V_4 \le V_{T80}$, pin 1 – 16	V _{limit}		8.6		V
Temperature monitoring, p	bin 4					
Input current		II			500	nA
80%-threshold		V _{T80}	390	420	450	mV
100%-threshold		V _{T100}	325	350	375	mV
Switch-off threshold		V _{TOFF}		$V_{S} - 1.8$		V
Operation mode selection,	pin 5	•				
	Pin 5 open $(I_5 = 0)$	V _{T5}		V _S /2		
Input current	$V_5 = V_{16}$	II		15		μΑ
	$V_5 = V_{12}$	-I _I		15		μΑ
Oscillator	·					
Input current	Pin 6	II	1		40	μΑ
Source voltage	$I_6 = -10 \mu\text{A}, \text{pin 6}$	V ₆		0.9		V
Upper saw tooth threshold	Pin 7	V _{Tmax}		9		V
Lower saw tooth threshold	Pin 7	V _{Tmin}		1.8		V
Oscillator frequency, see figu	ure 1					
	$C_4 = C_{osc} = 220 \text{ nF},$ $R_{11} = R_{osc} = 120 \text{ k}\Omega,$ pin 7	f _{osc}		1.1		Hz
Blink frequency	$V_{T100} < V_4 \le V_{T80}$, pin 1	f _{Blink}		2.2		Hz
Switching frequency, inter- val operation	$V_5 = V_{16}$, pin 14	f _s		1.1		Hz
Pulse ratio switch	Pin 14	t _p /T	0.2	0.23	0.26	

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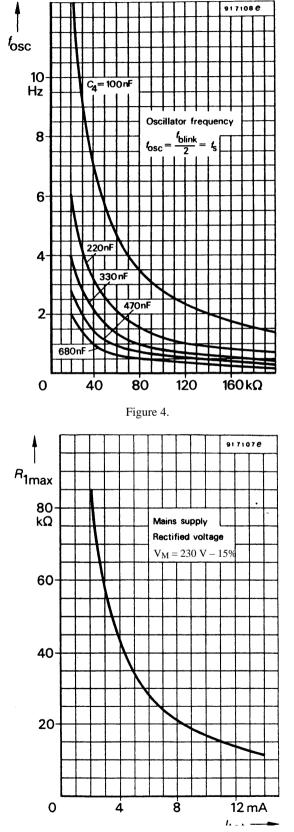


Figure 5.

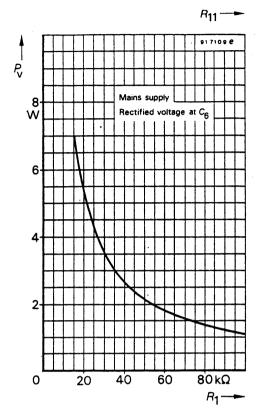


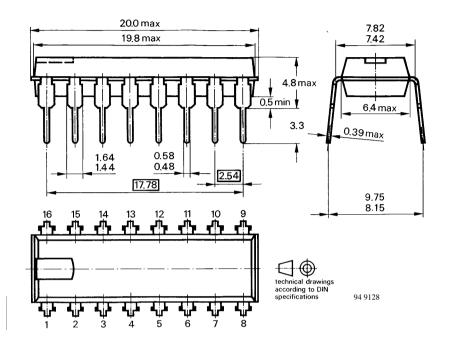
Figure 6.

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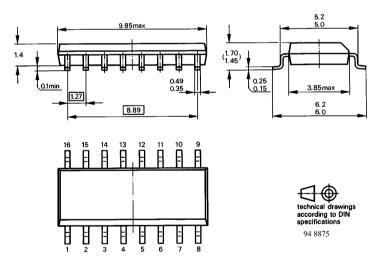
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Dimensions in mm:

Package: DIP16



Package: SO16



Ozone Depleting Substances Policy Statement

It is the policy of TEMIC TELEFUNKEN microelectronic GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

TEMIC TELEFUNKEN microelectronic GmbH semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

TEMIC can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

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